

Efficiency of F-center formation in pure and thallium activated KCl crystals by electron irradiation.

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The efficiency of F centre formation was determined for pure and Tl activated KCl crystals along the $\langle 100 \rangle$ and $\langle 110 \rangle$ directions. The observed efficiency values were found to be higher in case of Tl activated KCl, but the measured depth of electron penetration had been longer in pure KCl crystals.

1. INTRODUCTION

Numerous evidences are available on the mechanism of the defect formation by irradiating with X-rays or by any other ionising radiation (Seitz 1954, Compton & Schulman 1962). Investigations were made on the efficiency of formation of F-centers in alkali halide crystals (Rabin *et al* 1960, Ritz 1964, Hirai 1972) but no report on the dependence of F-center production efficiency on the crystallographic orientation is available in the literature. Moreover, the incorporation of foreign impurities such as Tl in KCl is expected to have an influence on the efficiency of F-center formation. But so far, a limited attention (Pooly 1966, Butterworth *et al* 1970) has been drawn on such type of studies, particularly in KCl : Tl crystals under electron irradiation. An investigation on this may help to get a deeper insight into the mechanism of absorption and emission of light by KCl : Tl phosphors.

Thin flakes of KCl $\langle 100 \rangle$, KCl $\langle 110 \rangle$, KCl : Tl $\langle 100 \rangle$ and KCl : Tl $\langle 110 \rangle$ were used for the present investigation. The absorption spectrum of KCl : Tl (0.01 At%) was obtained with the help of a Beckmann Spectrophotometer. Only one peak lying at $247 \text{ m}\mu$ was detected, but the other possible absorption peak at $196 \text{ m}\mu$ could not be observed with the same instrument. The emission spectrum peaking at $470 \text{ m}\mu$ for KCl : Tl under electron irradiation was obtained. The detection of other allowed emission band peaking at $305 \text{ m}\mu$ was not possible because of the limitations of the glass prism monochromator used for the present work. For a pure sample of KCl, no such luminescence under electron irradiation was observed at room temperature. Although the $470 \text{ m}\mu$ emission of KCl : Tl, has not been explained clearly yet some relevant explanations have been put forward by several authors (Anderson 1964, Sturge 1967, Delbecq 1966). According to a recent communication (Ranfagni 1972), the $470 \text{ m}\mu$ emission in KCl : Tl is due to single Tl^+ center.

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The crystals were irradiated with electrons in the energy range between 40 and 60 KeV at room temperature. *F*-centers were produced over the surface of the samples. The time of irradiation and the beam current were adjusted so as to ensure the formation of late stage coloration well below the saturation limit. The measurement of *F* absorption was carried out in a dark ambient using a RCA IP 21 photomultiplier with the conventional electronic circuits. *F* absorption bands were recorded for all the specimens under investigation (not shown). The efficiency of formation of *F*-center was calculated using the relation, $\eta = n_c \times E / n_F$ keV/centre. Where, n_c , E , n_F represent the number of incident electrons per cm² at an energy E , and the number of *F*-centers produced per cm². The results are shown in the given table 1

Table 1 Efficiency values for KCl and KCl:Tl along <100> and <110> directions under electron irradiation at room temperature

Sample	Energy of incident electron in KeV	No. of incident electrons per cm ² along		No of <i>F</i> -centers per cm ² along		Efficiency $\eta = \frac{n_c \times E}{n_F}$ measured in KeV per center along	
		<100>	<110>	<100>	<110>	<100>	<110>
KCl	40	1.06×10^{14}	1.17×10^{14}	1.77×10^{15}	1.41×10^{15}	2.4	3.30
	50	1.26×10^{14}	7.68×10^{13}	2.31×10^{15}	1.24×10^{15}	2.7	3.09
	60	1.49×10^{14}	8.02×10^{13}	2.99×10^{15}	1.56×10^{15}	3.0	3.08
	40	1.40×10^{14}	1.46×10^{14}	5.20×10^{14}	5.24×10^{14}	10.8	11.40
	50	1.30×10^{14}	1.74×10^{14}	6.00×10^{14}	6.72×10^{14}	10.8	12.60
	60	1.39×10^{14}	1.40×10^{14}	7.12×10^{14}	7.03×10^{14}	11.7	11.90
KCl:Tl							

Further the depth of electron penetration was measured by observing the gradual decrease of optical density (due to coloration) on successive removal of surface layers of the specimen. The removal of surface layers was done by wet cut process. The depth of electron penetration was measured for various electron energies in pure KCl and Tl activated KCl. The results are shown in table 2

Table 2. Electron energy versus the depth of electron penetration at room temperature

Energy in KeV	Depth of electron penetration in micron along	
	KCl <100>	KCl:Tl <100>
40	15	10
50	20	13
60	26	15

5. DISCUSSION

The results as given in table 1 show that the efficiency values for pure KCl under electron irradiation do not appreciably change with the change of energy of the incident electrons. Practically no appreciable difference is found in the efficiency values for pure KCl<100> and KCl<110> crystals and a similar trend of result is found for Tl activated KCl crystals. In the present case, the fluctuations of the results are found to be of the similar order as developed in other works (Hermann *et al* 1970). But there is a marked difference in the measured F -center efficiency (η) values between pure and activated samples of KCl. The increase of efficiency values due to the presence of Tl in KCl gives rise to lowering of F -center production rate, but at the same time it produces luminescence which is almost absent in pure KCl crystal.

The diminution of coloration (table 1) in KCl : Tl crystals may be attributed to the suppression of late stage coloration by the Tl^+ ions. It may be seen (table 2) that the depth of electron penetration for a particular energy is depth of electron penetration for a particular energy is longer in pure KCl than in KCl : Tl. The electron energy loss ($-dE/dx$) in pure KCl is primarily due to production of color centers. But the energy loss in Tl-activated KCl is due to color center formation as well as due to luminescence emission. An estimate of the energy loss due to F -center formation in KCl crystal may be made from the data given in table 2. But in case of KCl : Tl crystal, the energy loss can not be determined for want of relevant data available on the energy loss associated with the process of luminescence. Perhaps, this may be achieved by determining the quantum efficiency for KCl : Tl samples under electron-irradiation.

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